Diode Semiconductor Device - Page 1 of 1

AeroBase Group

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# Inclosure Material:

Glass

# Function For Which Designed:

Microwave

# End Application:

Aircraft, f-11; strategic weapon systems (poseidon and trident); los angeles class ssn (688); spruance class dd (963); wasp class lhd; tarawa class lha; yellowstone class ad-41; general purpose electronic test equipment gpete; forrestal class cv; emory s. Land class as

# Features Provided:

Hermetically sealed case

# Criticality Code Justification:

Feat

## Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

20.0 breakover voltage, dc

## Capacitance Rating In Picofarads:

2.2

### **Special Features:**

Weapon system essential

## Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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